NSN 5961-01-555-1087

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No Fiig: A110a0



View Online at https://aerobasegroup.com/nsn/5961-01-555-1087 **Inclosure Material:** Metal **Overall Length:** 1.573 inches **Overall Height:** Between 0.250 inches and 0.450 inches Overall Width: 1.050 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-3 **Electrode Internally-electrically Connected To Case:** Cathode **Mounting Method:** Unthreaded hole **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 120.0 breakdown voltage, collector-to-base, emitter open and 120.0 breakdown voltage, collector-to-emitter, base open and 5.0 emitter to base voltage, static, collector open **Current Rating Per Characteristic:** Between 1.00 amperes source cutoff current and 30.00 amperes source cutoff current **Power Rating Per Characteristic:** 200.0 watts small-signal input power, common-collector absolute **Transfer Ratio:** 200.0 static forward current transfer ratio, common-emitter **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius ambient air **Special Features:** Junction pattern arrangement: npn **Terminal Type And Quantity:** 2 pin Shelf Life: N/a **Unit Of Measure: Demilitarization:**